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Term:

((438/620)!.CCLS.)

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USPT	((438/620)!.CCLS.)	120	<u>L13</u>
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USPT	L10 and first and second and (insulating or dielectric) and (metal or conductive)	1047	<u>L11</u>
USPT	L9 and level	2084	<u>L10</u>
USPT	L8 and semiconductor	3280	<u>L9</u>
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USPT	DRAM and (method.ti.)	7971	<u>L7</u>
USPT	DRAM	22959	<u>L6</u>
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USPT	oxide and gate and first and second and (opening\$1 or via\$1) and (bit adj line) and junction	1677	<u>L4</u>
USPT	oxide and gate and first and second and (opening\$1 or via\$1) and (bit adj line) and junction and ((multi-level or multilevel or multi adj level) with metallization)	7	<u>L3</u>
USPT	((438/622)!.CCLS.)	363	<u>L2</u>
USPT	(5753391 or 5701013).pn.	2	<u>L1</u>